



### **General Description**

The WSK140N08 is the highest performance trench N-Ch MOSFET with extreme high cell density, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications.

### **Product Summery**

BV <sub>DSS</sub>	R <sub>DSON</sub>	I <sub>D</sub>
80V	4.8mΩ	140A

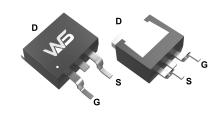
### **Applications**

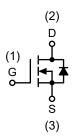
Power Management for Inverter Systems.

#### **Features**

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

### **TO-263-2L Pin Configuration**





### **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit		
Common	Ratings (T <sub>C</sub> =25°C Unless Otherwise Noted)			•	
$V_{DSS}$	Drain-Source Voltage	80	V		
$V_{GSS}$	Gate-Source Voltage		±25	<b>一 '</b>	
T <sub>J</sub>	Maximum Junction Temperature		175	°C	
T <sub>STG</sub>	Storage Temperature Range	Storage Temperature Range		°C	
I <sub>S</sub>	Diode Continuous Forward Current	T <sub>C</sub> =25°C	140	А	
Mounted	on Large Heat Sink				
I <sub>DM</sub>	Pulsed Drain Current *	T <sub>C</sub> =25°C	551**	А	
I <sub>D</sub>	Continuous Drain Current	T <sub>C</sub> =25°C	140	A	
		T <sub>C</sub> =100°C	91		
$P_D$	Maximum Power Dissipation	T <sub>C</sub> =25°C	250	107	
		T <sub>C</sub> =100°C	125	─ W	
$R_{\theta JC}$	Thermal Resistance-Junction to Case		0.61	°C/W	
$R_{\theta JA}$	Thermal Resistance-Junction to Ambient		62.5		
Avalanch	e Ratings			•	
E <sub>AS</sub>	Avalanche Energy, Single Pulsed	L=0.5mH	762***	mJ	

Note: \* Repetitive rating; pulse width limited by junction temperatur

<sup>\*\*</sup> Drain current is limited by junction temperature

<sup>\*\*\*</sup> VD=64V



# **Electrical Characteristics** $(T_c = 25^{\circ}C \text{ Unless Otherwise Noted})$

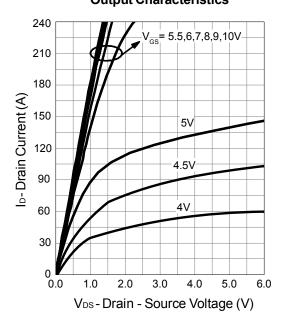
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit		
Static Cha	Static Characteristics							
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS}$ =0V, $I_{DS}$ =250 $\mu$ A	80	-	-	V		
	Zero Gate Voltage Drain Current	$V_{DS}$ =80V, $V_{GS}$ =0V	-	-	1	<u>μ</u> Α		
I <sub>DSS</sub>		T <sub>J</sub> =85°C	-	-	10			
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$ , $I_{DS}=250\mu A$	2.0	3.0	4.0	V		
I <sub>GSS</sub>	Gate Leakage Current	$V_{GS}=\pm 25V$ , $V_{DS}=0V$	-	-	±100	nA		
R <sub>DS(ON)</sub> *	Drain-Source On-state Resistance	V <sub>GS</sub> =10V, I <sub>DS</sub> =70A	-	4.8	6.0	mΩ		
Diode Characteristics								
V <sub>SD</sub> *	Diode Forward Voltage	I <sub>SD</sub> =70 A, V <sub>GS</sub> =0V	-	0.8	1.2	V		
t <sub>rr</sub>	Reverse Recovery Time	I 70 A II / II 400 A / -	-	30	-	ns		
Q <sub>rr</sub>	Reverse Recovery Charge	$I_{SD}$ =70A, $dI_{SD}/dt$ =100A/ $\mu$ s	-	52	-	nC		
Dynamic (	Characteristics							
R <sub>G</sub>	Gate Resistance	V <sub>GS</sub> =0V,V <sub>DS</sub> =0V,F=1MHz	-	1.6	-	Ω		
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V,	-	4687	-	pF		
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> =25V,	-	665	-			
C <sub>rss</sub>	Reverse Transfer Capacitance	F=1.0MHz	-	235	-			
t <sub>d(ON)</sub>	Turn-on Delay Time		-	26	-			
T <sub>r</sub>	Turn-on Rise Time	$V_{DD}=40V, R_G=6\Omega,$	-	17	-	ns		
t <sub>d(OFF)</sub>	Turn-off Delay Time	I <sub>DS</sub> =70A, V <sub>GS</sub> =10V,	-	41	-			
T <sub>f</sub>	Turn-off Fall Time		-	53	-			
Gate Chai	Gate Charge Characteristics							
Qg	Total Gate Charge		-	115	-			
$Q_{gs}$	Gate-Source Charge	V <sub>DS</sub> =64V, V <sub>GS</sub> =10V, I <sub>DS</sub> =70A	-	15	-	nC		
$Q_{gd}$	Gate-Drain Charge	טייט - י טיי	-	44	-			
	•	-						

Note \* : Pulse test ; pulse width  $\leq$ 300 $\mu$ s, duty cycle  $\leq$ 2%.

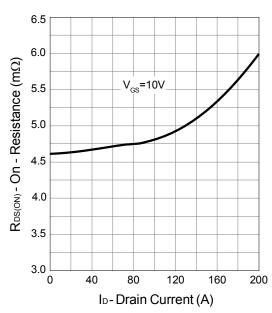


### **Typical Operating Characteristics**

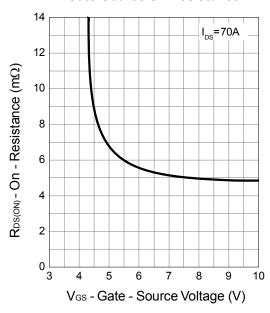
## Output Characteristics



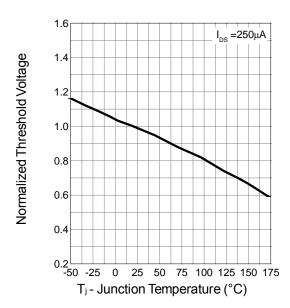
#### **Drain-Source On Resistance**



#### **Gate-Source On Resistance**



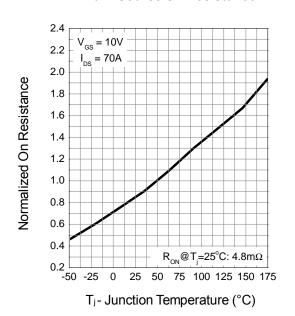
### **Gate Threshold Voltage**



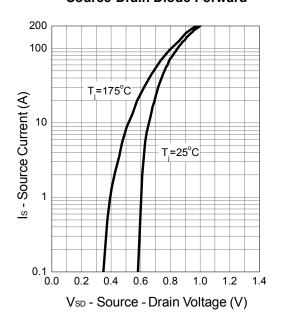


### **Typical Operating Characteristics (Cont.)**

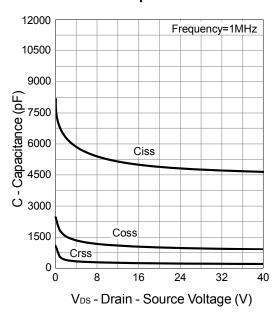
### **Drain-Source On Resistance**



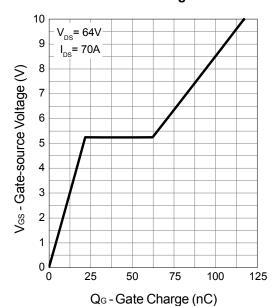
#### **Source-Drain Diode Forward**



### Capacitance

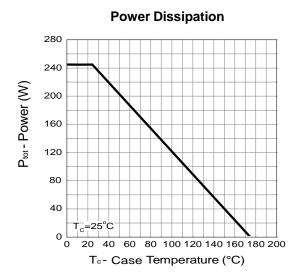


### **Gate Charge**





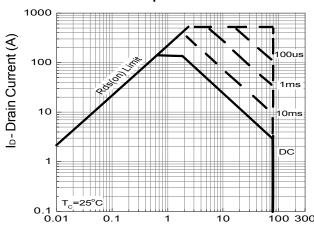
### **Typical Operating Characteristics (Cont.)**



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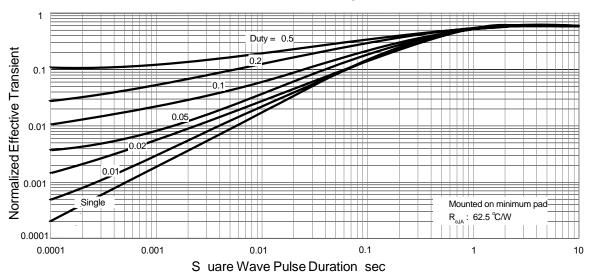
T<sub>c</sub>-Case Temperature (°C)

### **Safe Operation Area**



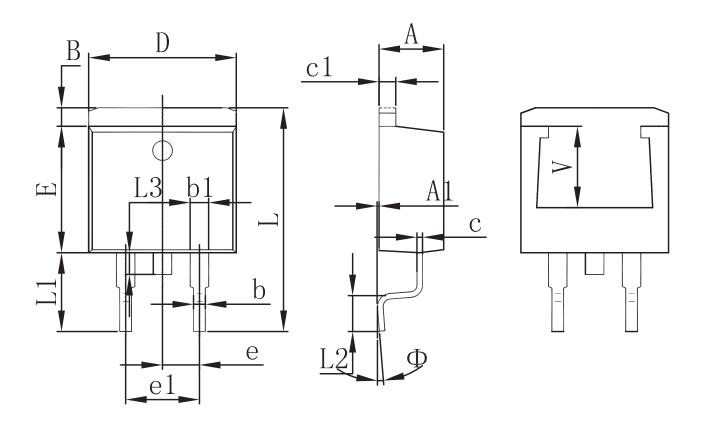
V<sub>DS</sub> - Drain - Source Voltage (V)

### **Thermal Transient Impedance**





## **Packaging information**



Cymbol	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
А	4.470	4.670	0.176	0.184
A1	0.000	0.150	0.000	0.006
В	1.120	1.420	0.044	0.056
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
С	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
е	2.540	TYP.	0.100 TYP.	
e1	4.980	5.180	0.196	0.204
L	14.940	15.500	0.588	0.610
L1	4.950	5.450	0.195	0.215
L2	2.340	2.740	0.092	0.108
L3	1.300	1.700	0.051	0.067
Ф	0°	8°	0°	8°
V	5.600 REF.		0.220REF.	



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